

Status of the JLab IR/UV Upgrade

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**Jefferson Lab
Newport News, Virginia**

**LPC
Newport News
March 9, 2005**

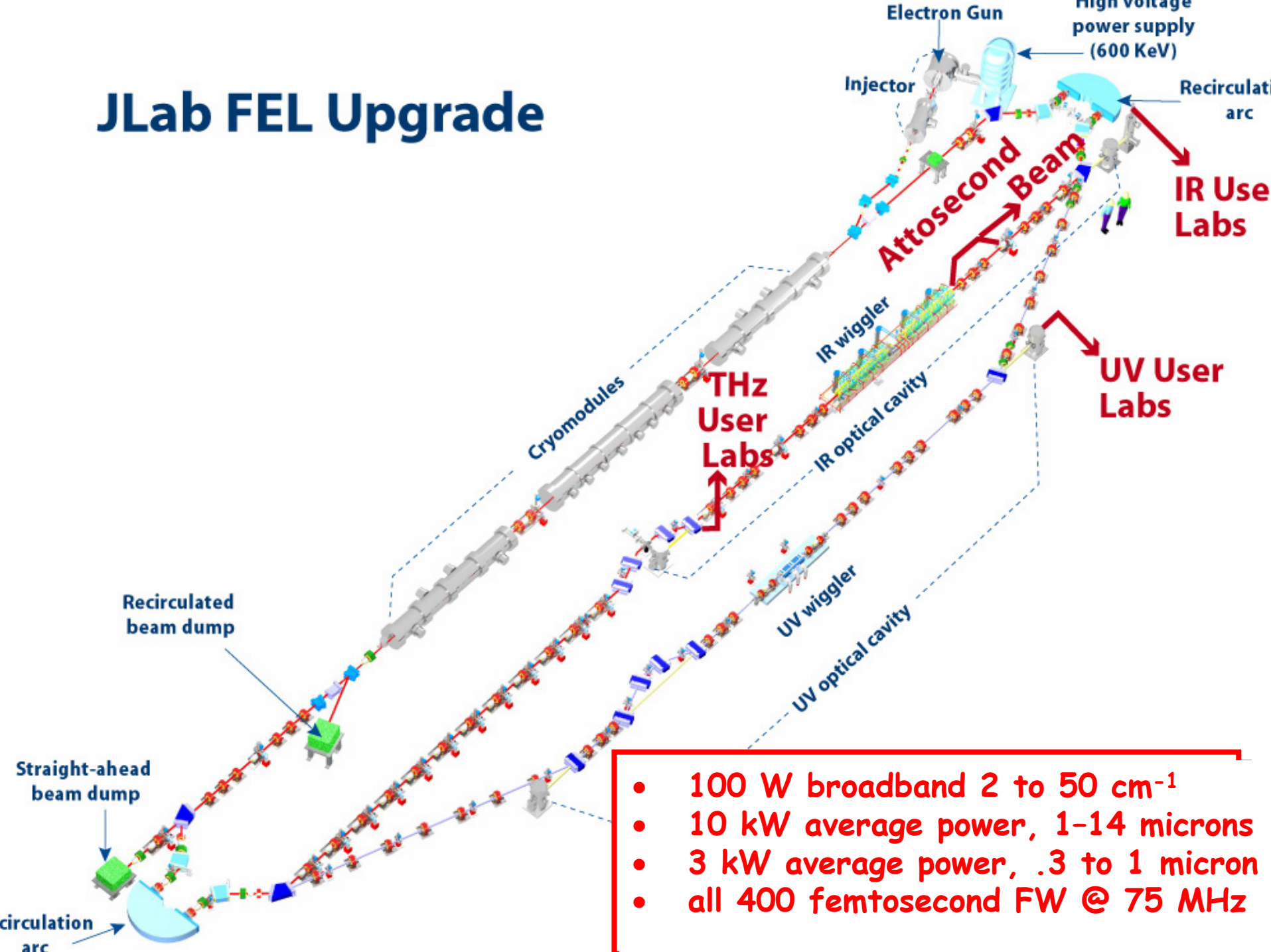


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JLab FEL Upgrade



- 100 W broadband 2 to 50 cm^{-1}
- 10 kW average power, 1-14 microns
- 3 kW average power, .3 to 1 micron
- all 400 femtosecond FW @ 75 MHz

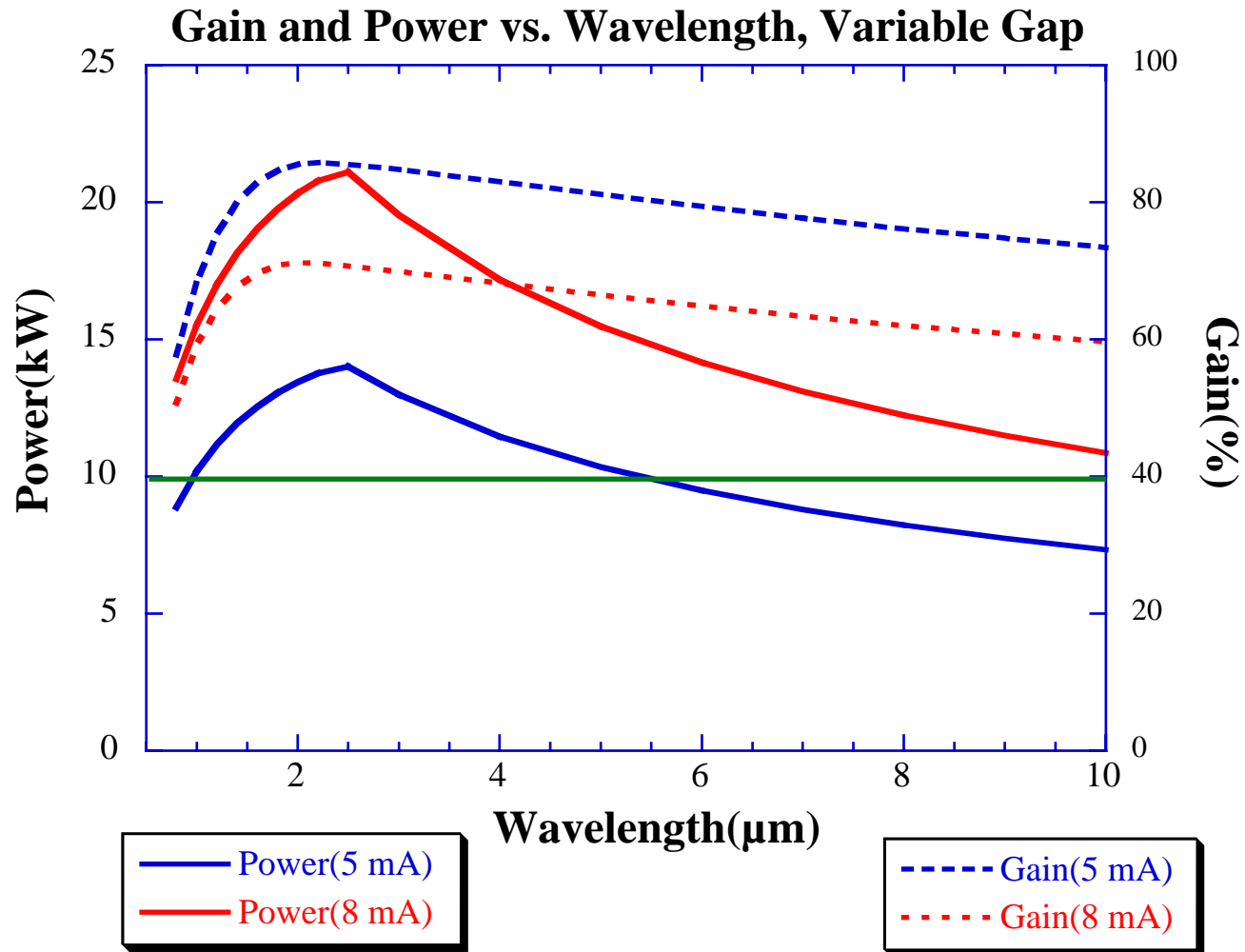
JLab FEL Upgrade Status

- . THz system installed and ready to begin user experiments
- . IR Upgrade FEL at JLab starting up at 10 kW
 - . Characterization has begun : 10 kW average power lasing achieved at 6 microns
 - . Lased at moderate powers at 2.8 - 3microns with broadband mirrors
 - . User experiments getting ready; have provided alignment beam into Lab 1
- . UV installation this year
 - . User experiments late next fall
- . Some setbacks: lost some gradient capability in linac; may not be able to make 1 micron at full power or UV lasing on fundamental until replacement cryomodule is ready. User program will continue:
 - . Third harmonic 1 micron lasing
 - . 700 nm lasing and doubled

IR Upgrade Specifications

- Average Power > 10,000 W
- Wavelength range 1 to 14 μm
- Micropulse energy > 100 μJ , in pulse train 50 μs to CW, arbitrary prf
- Micropulse length $\sim 0.1\text{-}2$ ps FWHM (adjustable)
- PRF 74.85 MHz $\div 2x$ down to 4.68 MHz
- Bandwidth $\sim 0.2\text{--}3$ % (always Fourier transform limited!)
- Position/Angle jitter < 100 μm , 10 μrad
- Polarization linear, > 1000:1
- Transverse mode < 2x diffraction limit. Gaussian profile
- Beam dia. at lab 2 - 6 cm, wavelength dependent

Performance with Variable Gap PM Wiggler

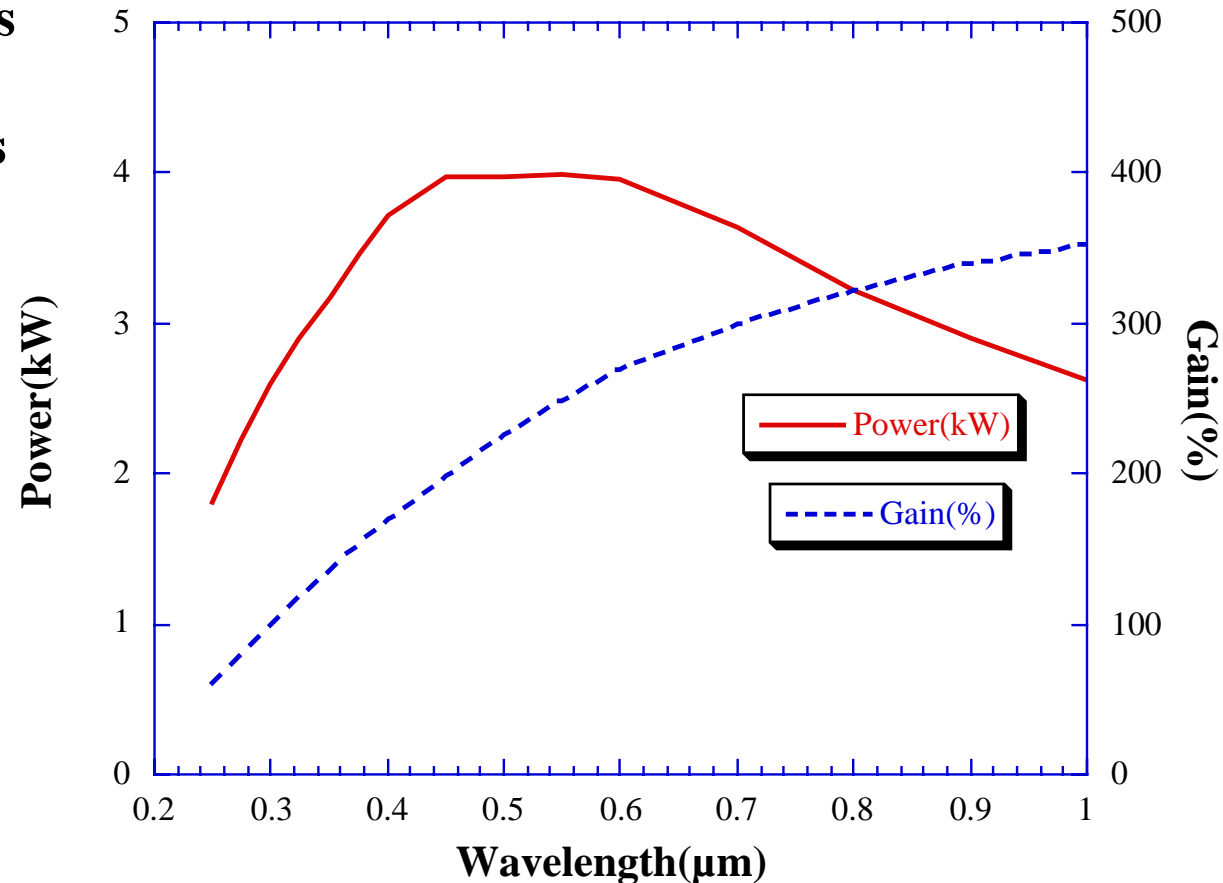


Minimum beam energy=80 MeV, Energy <160 MeV. Energy spread constant

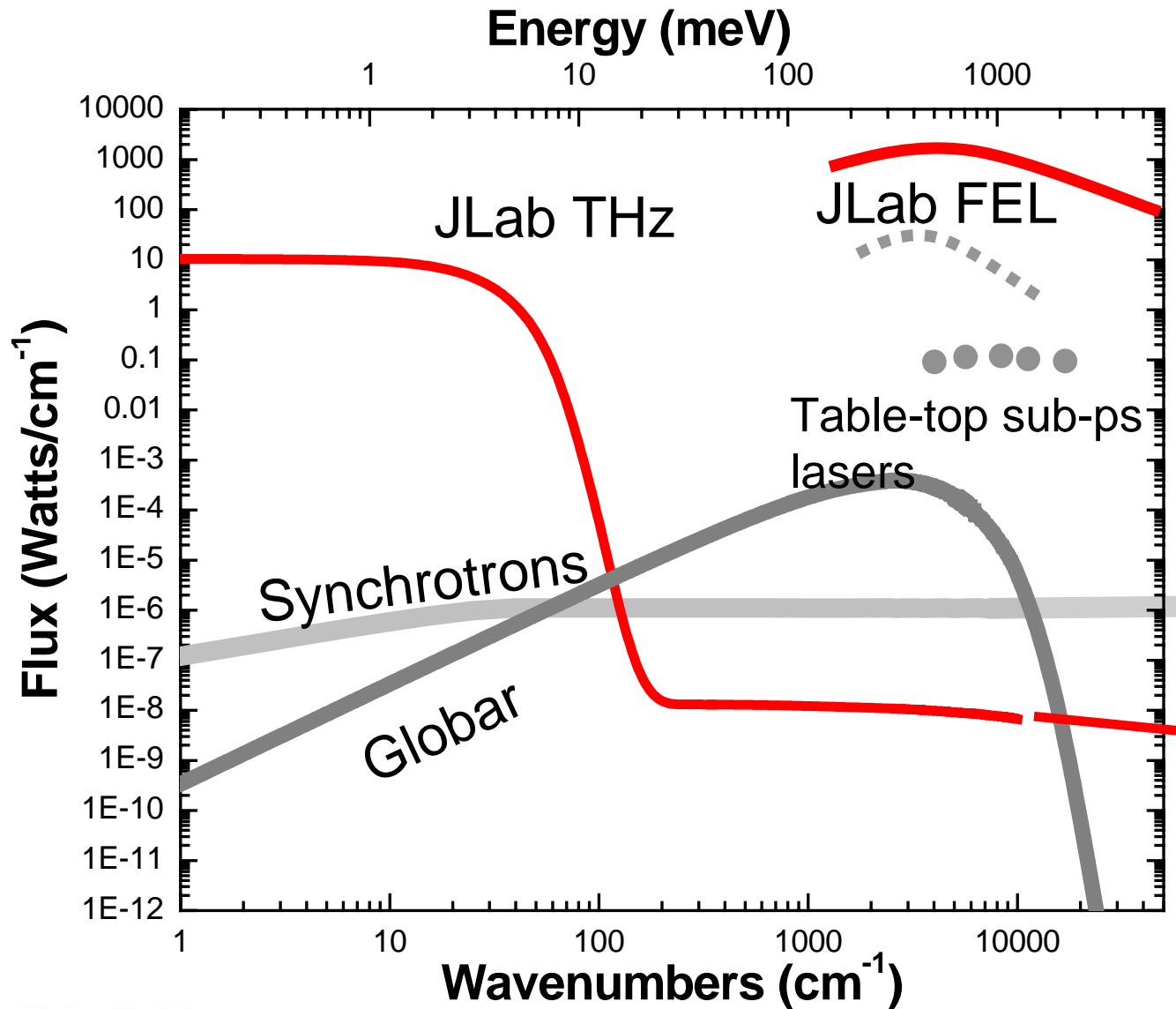
UV Upgrade Performance: Installation next summer

- Tunable pulse energy to saturate electronic transitions
- Drive non-linear field effects
- High rep rate for S/N: e.g., molecular beams, gas phase

UV Upgrade Power and Gain



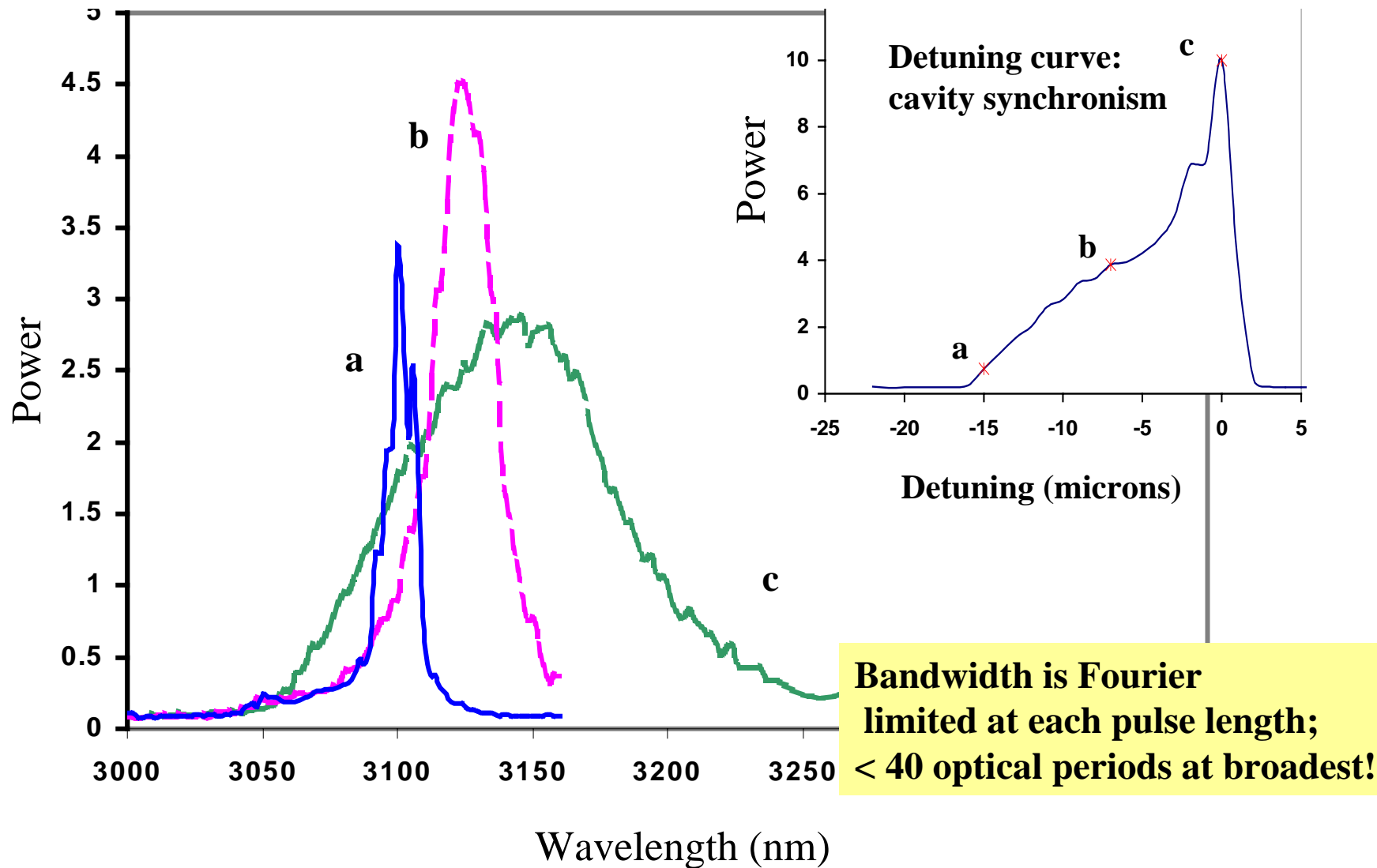
High power THz with sub-picosecond pulses is produced parasitically from electron beam



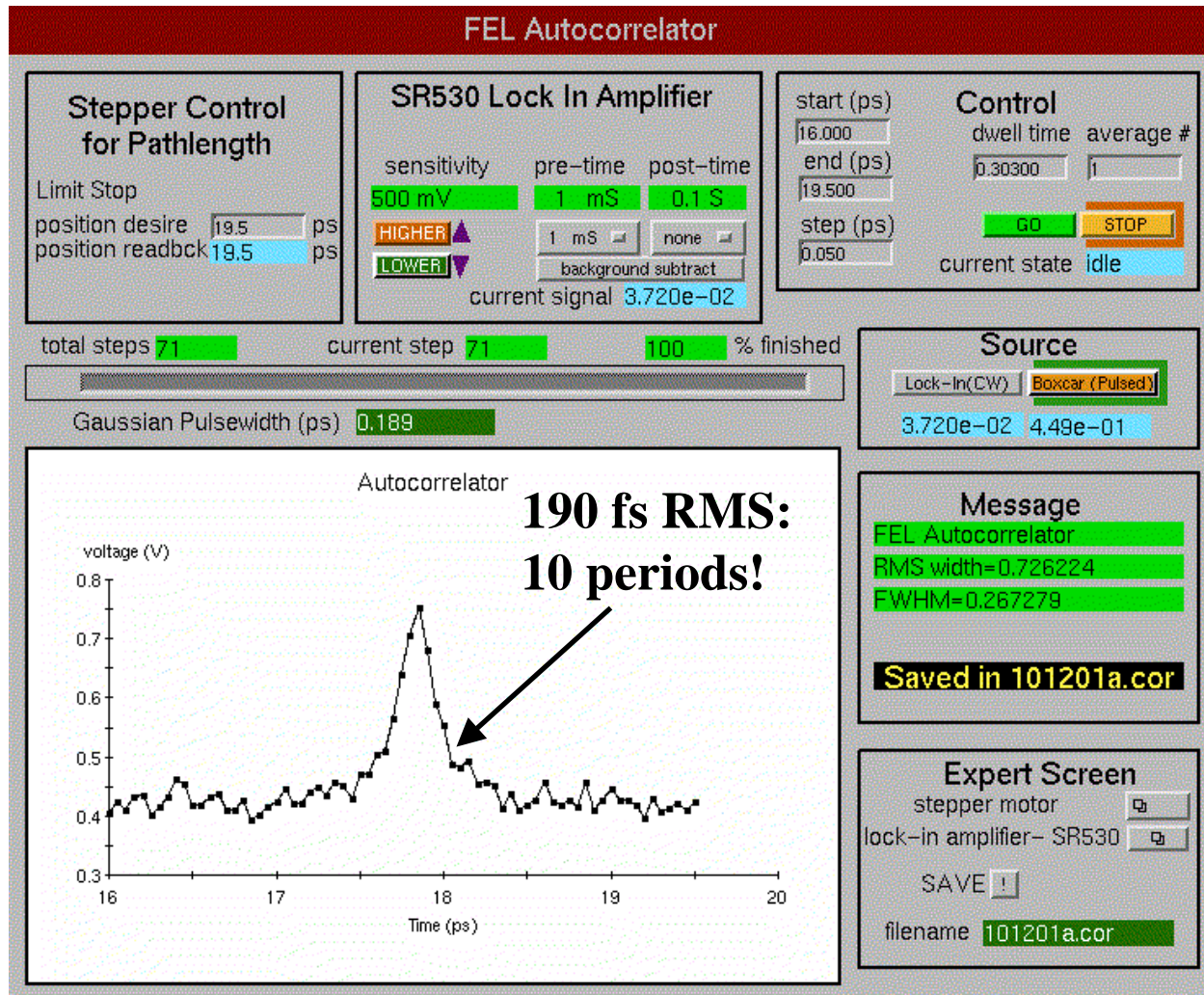
FEL proof of principle:
Neil et al. Phys. Rev. Letts **84**, 662 (2000)

THz proof of principle:
Carr, Martin, McKinney, Neil, Jordan & Williams
Nature **420**, 153 (2002)

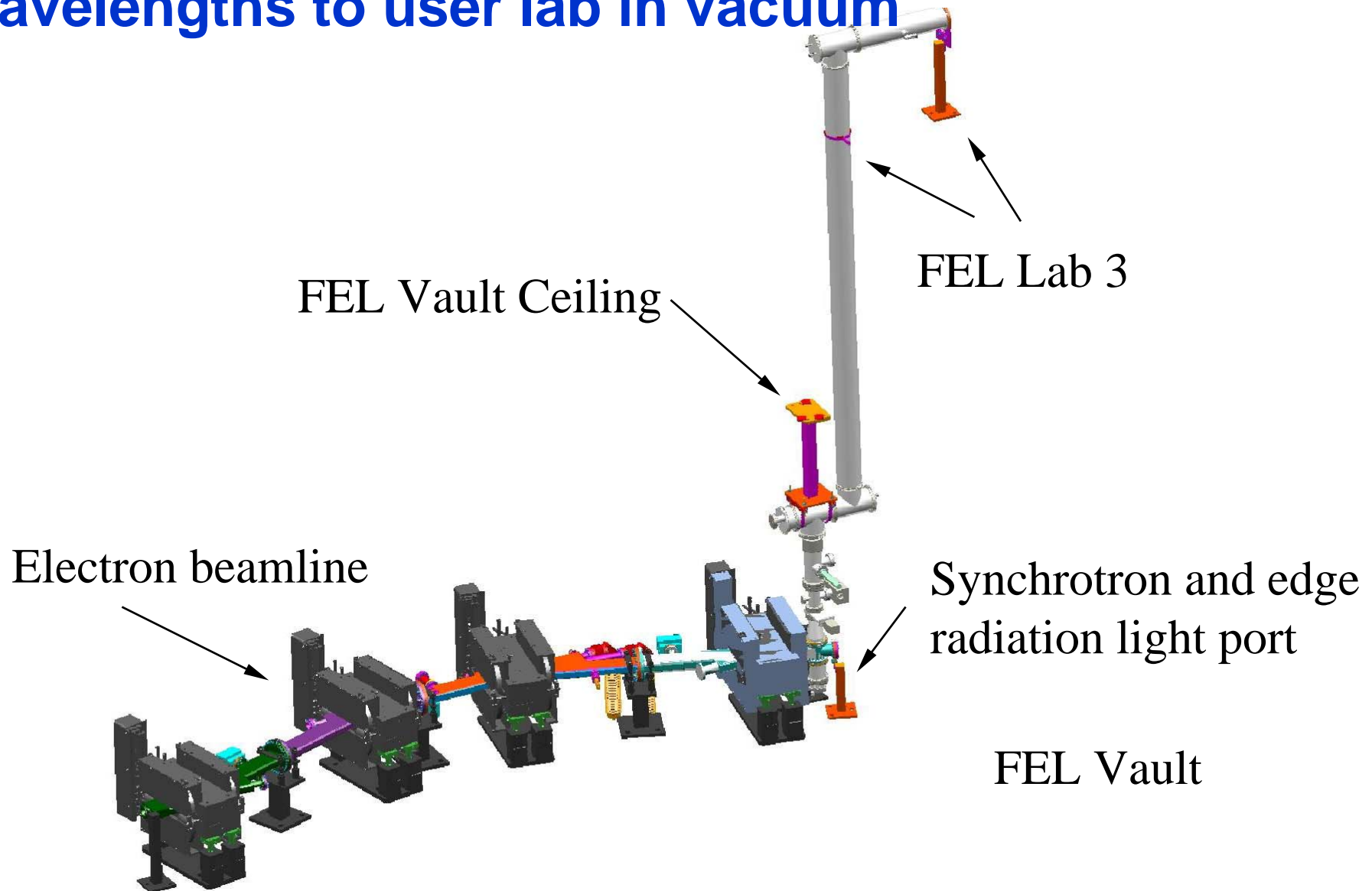
IR Demo measured bandwidth varies as a function of optical cavity length



Many studies use ultrashort pulses: IR Demo autocorrelation data

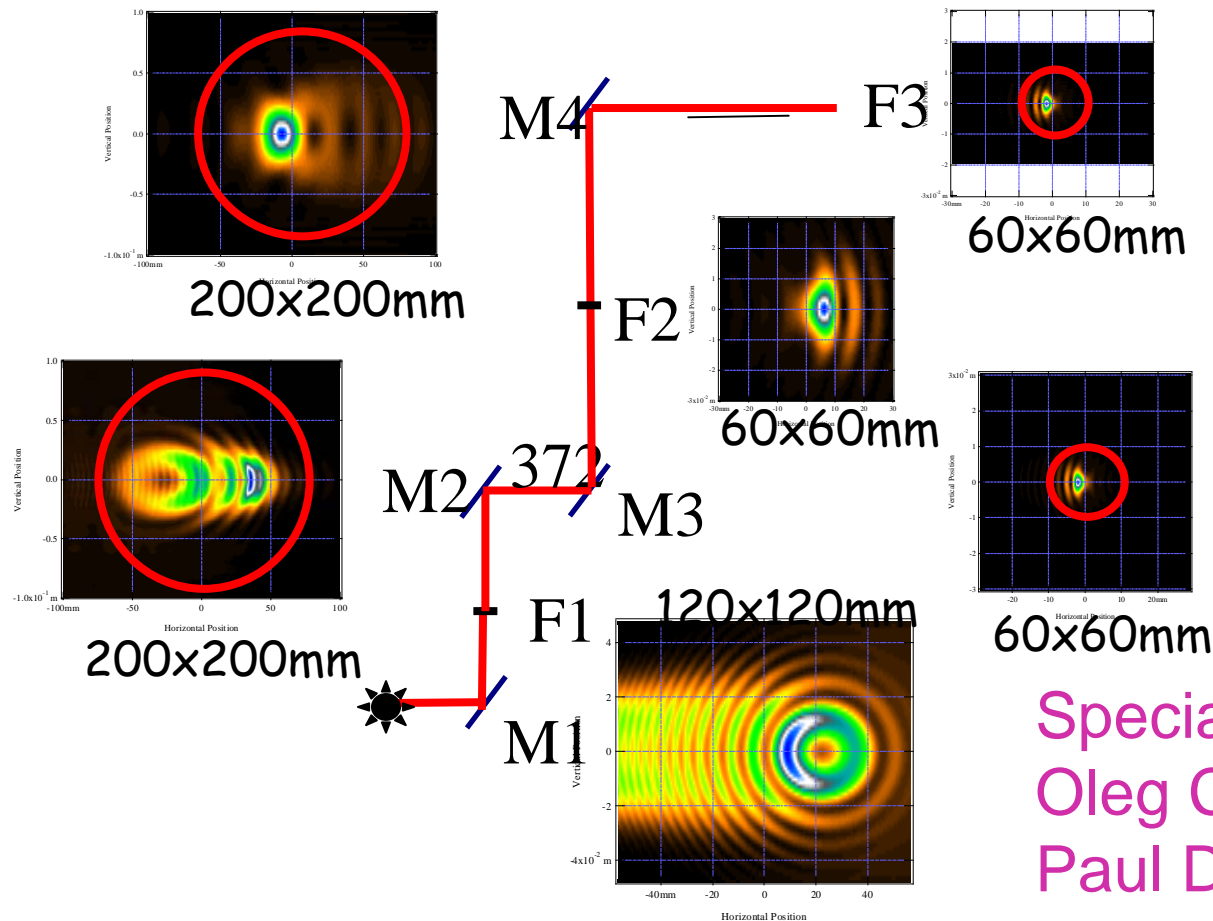


Terahertz beamline transports visible to 5 mm wavelengths to user lab in vacuum



See G. Williams, MM4.3

JFEL THz Beamline Calculated Optical Beam Patterns



Special thanks to
Oleg Chubar,
Paul Dumas.

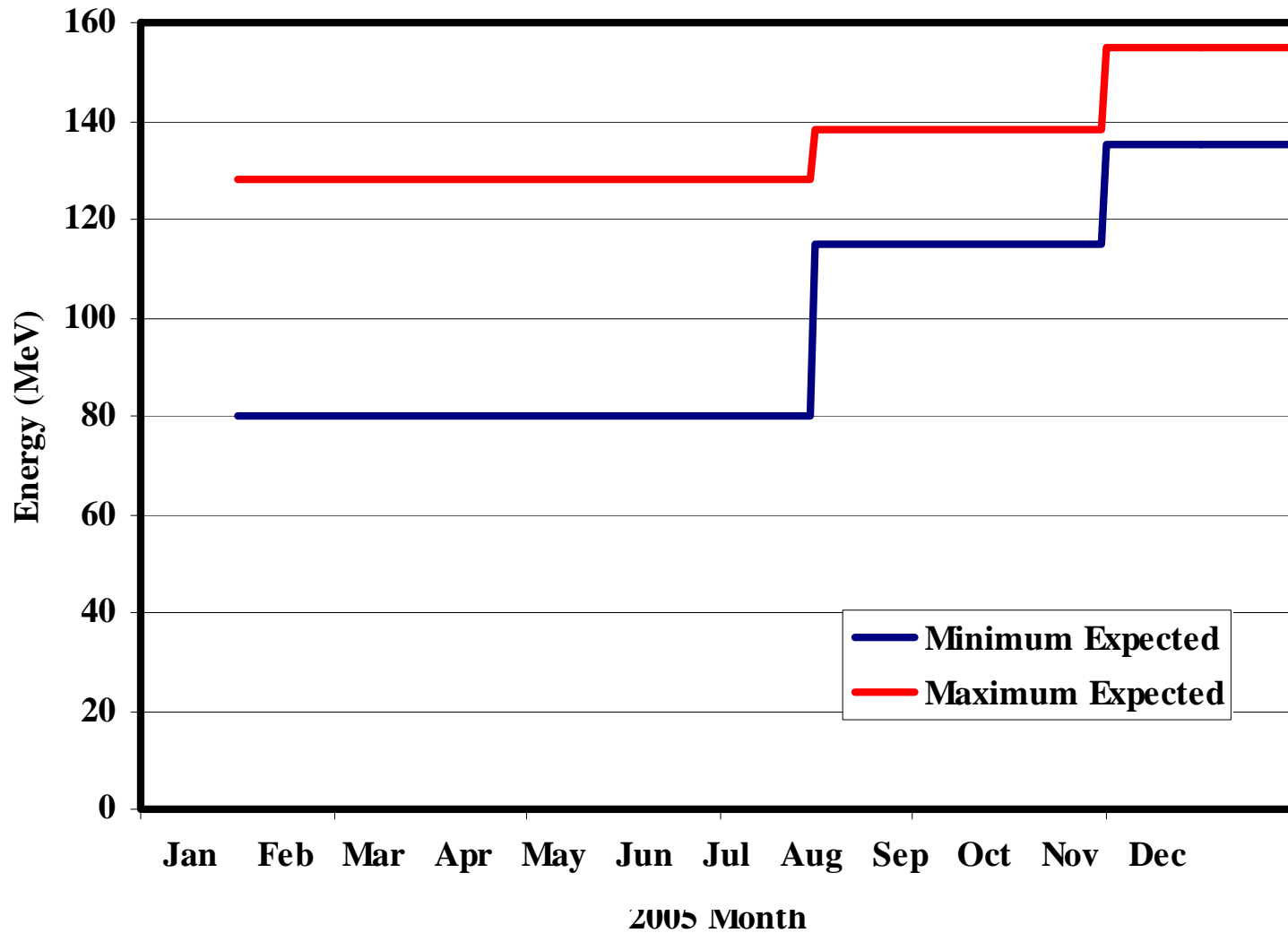
Lasing Capability – IR Upgrade

- We have several sets of high power mirrors capable of multi-kW but these are narrow band
 - 6 microns, 2.8 microns, 1 microns, (1.6 microns, (2.2 microns on order)
- We also have hole outcouplers and broadband mirrors for lasing from 1 to 10 microns at ~ 50 W output
- Instantaneous tuning is limited only by wiggler (K^2 goes from ~0.7 to 1.1)
- Alignment light has been brought up to Lab 1 and the facility is essentially ready for User experiments

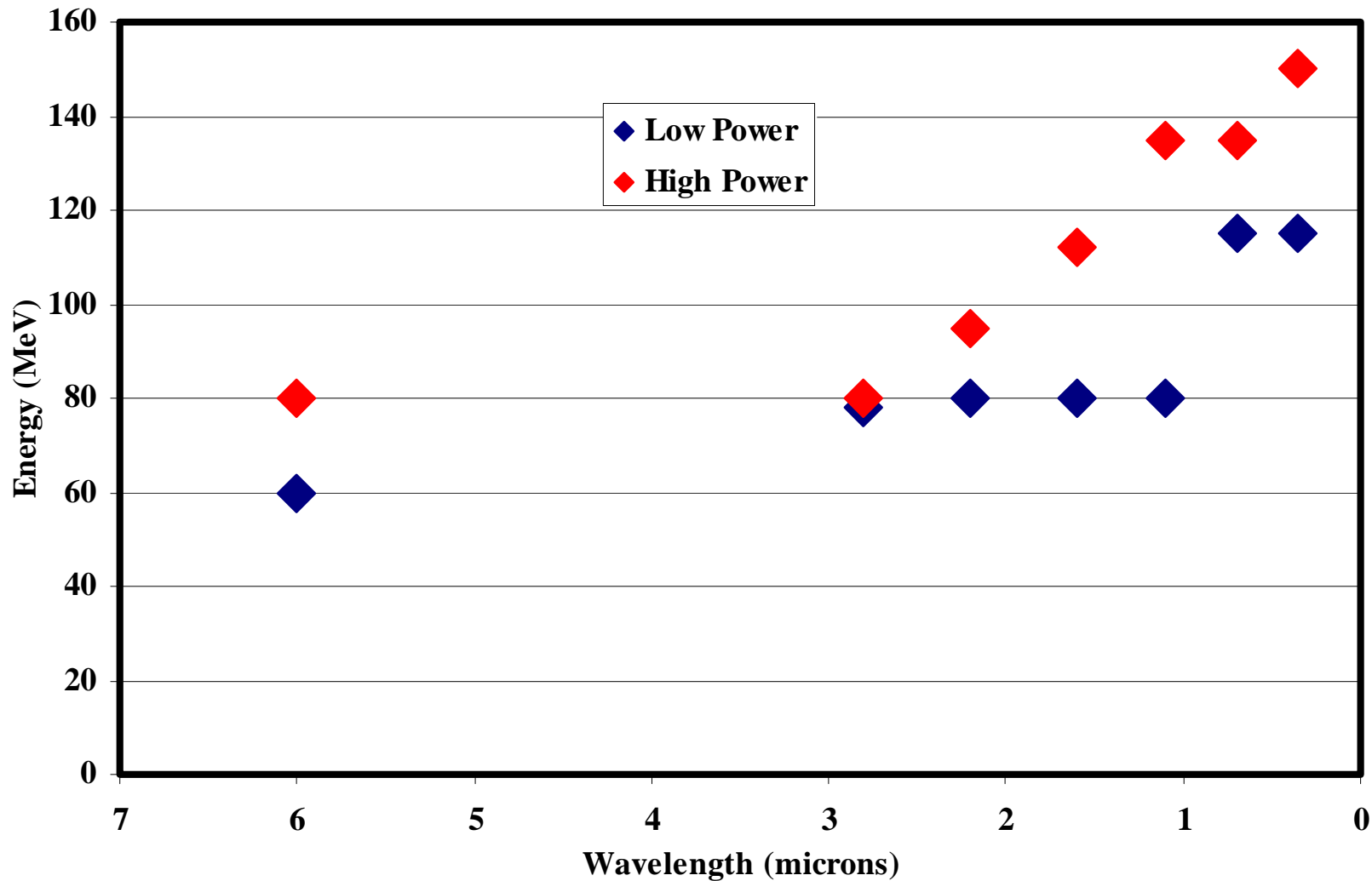
Capability projections – the bad news

- We have several ailing srf cavities that have reduced our energy capability. This will negatively impact the wavelength and power we can achieve
- Exact performance limits are not known at this time; a number of possible approaches and fixes are under investigation; we will know more in the next few weeks
- Additional srf modules may be available in June (standard design) and September (high gradient)
- We also have additional wigglers under procurement and the option of doubling and tripling the FEL output as well as lasing on the third harmonic
- The following slides broadly summarize our expectations; low power means 10's to a few hundred W, high power means multiple kW

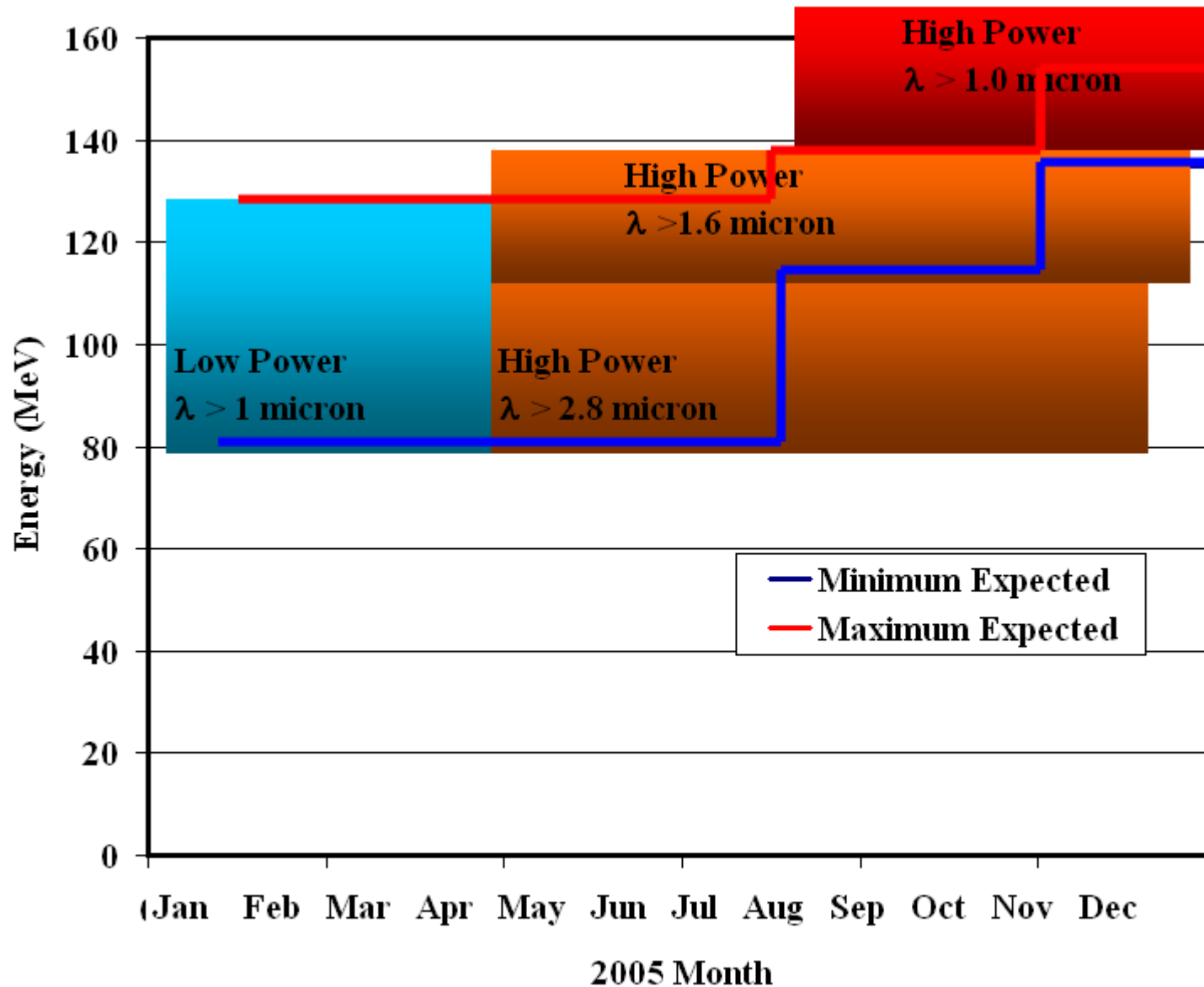
Projected energy available



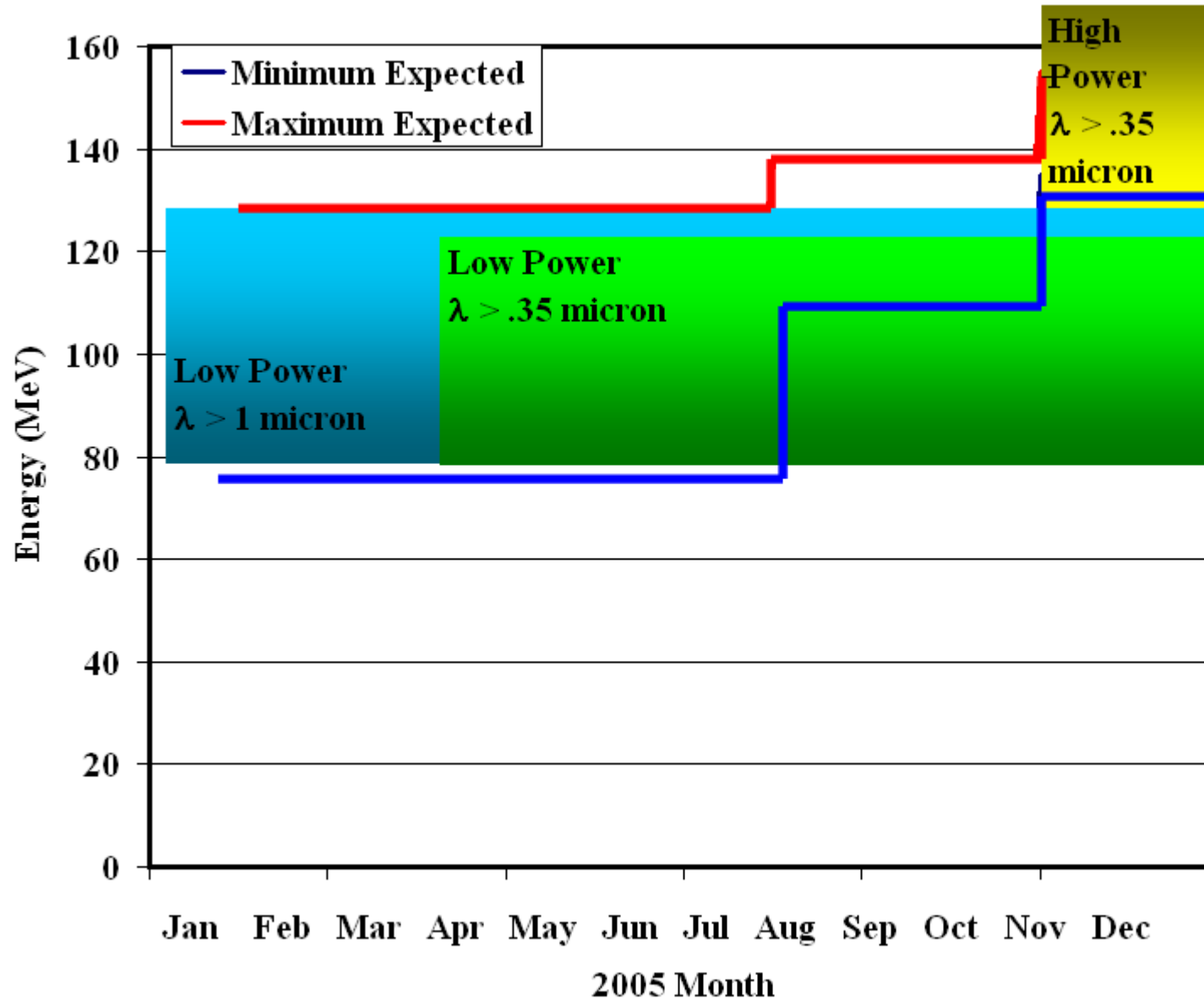
Energy requirements for specific programs



Lasing Capability – IR Upgrade



Future plans – UV Upgrade



Summary

- JLab Upgrade FEL is coming on line as a user facility with THz, IR, and (soon) UV light
 - Broadly tunable
 - Sub-picosecond pulses
 - Excellent beam quality
 - Unmatched power, pulse energies
 - (also have conventional lasers synchronized with FEL)

We are about ready to put first IR light into a User Lab

- The capabilities of this facility will gradually be increasing over the next year in terms of short wavelength operation and higher power capability



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The work discussed was performed by the FEL Team:

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With the help of lots of others at JLab



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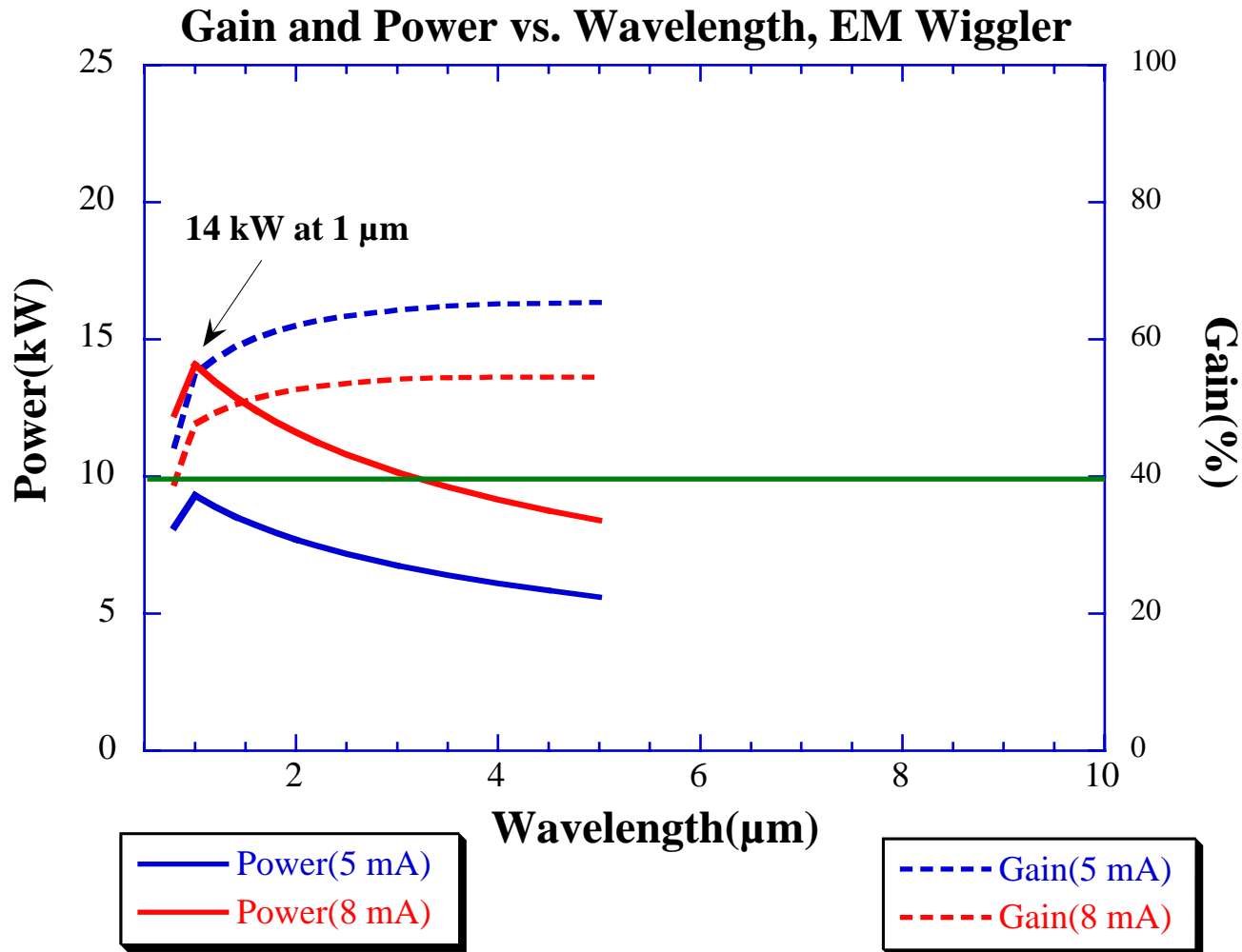


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Spreadsheet Model Predictions for EM Wiggler



No absorption in mirrors assumed in these calculations. Minimum energy=70 MeV, Max K=1.115. Energy spread constant. Can't guarantee operation longer than 4 μm .